

### Features

- Non-contact switching.
- For direct PC board or dual-in-line socket mounting.
- Fast switching speed.
- Reflective object sensor.

### Application

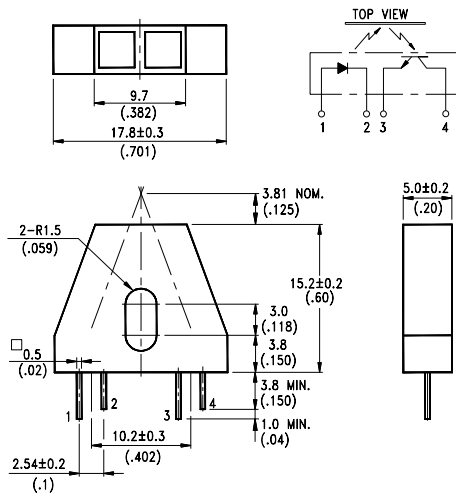
- FAX machine
- Printer
- COPY machine
- Counter

### Description

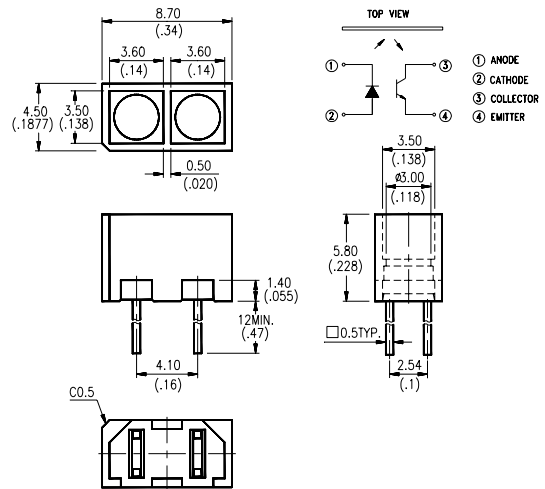
The LTH-209-01/LTH-1550-01/LTH-1650-01 reflective object sensors consist of an infrared emitting diode and a NPN silicon phototransistor mounted side by side on converging optical axis in a black plastic housing.

### Package Dimensions

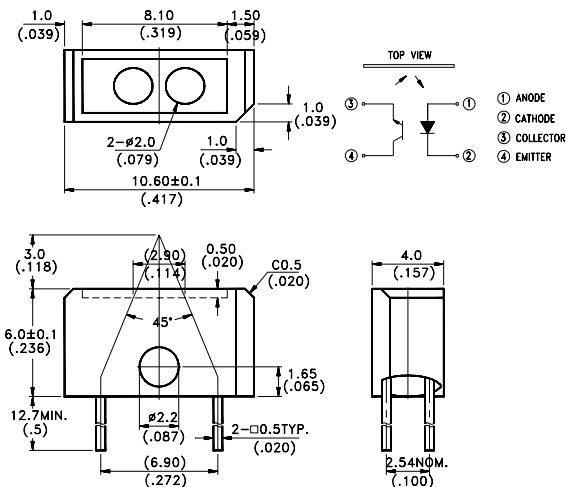
LTH-209-01



LTH-1550-01



LTH-1650-01



### Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is  $\pm 0.25$  mm (.010").
3. Lead spacing is measured where the leads emerge from the package.
4. Specifications are subject to change without notice.

## Absolute Maximum Rating at Ta=25°C

Parameter		Symbol	Maximum Rating	Unit
Input LED	Continuous Forward Current	I <sub>F</sub>	60	mA
	Reverse Voltage	V <sub>R</sub>	5	V
	Peak Forward Current (Pulse Wide=10 μs, 300PPS)	I <sub>CP</sub>	1	A
	Power Dissipation	P <sub>D</sub>	75	mW
Output phototransistor	Collector Current	I <sub>C</sub>	20	mA
	Power Dissipation	P <sub>C</sub>	100	mW
	Collector-emitter Voltage	V <sub>CEO</sub>	30	V
	Emitter-collector Voltage	V <sub>ECO</sub>	5	V
Operating Temperature Range		T <sub>opr</sub>	-25°C to + 85°C	
Storage Temperature Range		T <sub>stg</sub>	-40°C to + 100°C	
Lead Soldering Temperature [1.6mm(.063 in.)from body]		T <sub>s</sub>	260°C for 5 Seconds	

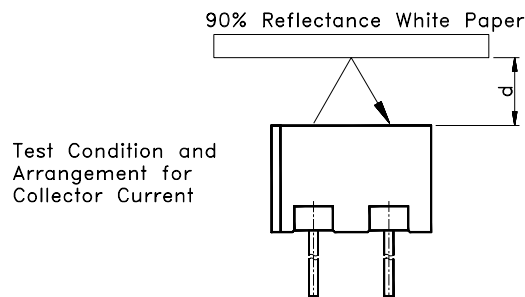
## Electrical Optical Characteristics at Ta=25°C

Parameter	Symbol	Part No.	Min.	Typ.	Max.	Unit	Test Condition	Bin No.		
Input LED										
Forward Voltage	V <sub>F</sub>			1.2	1.6	V	I <sub>F</sub> =20mA			
Reverse Current	I <sub>R</sub>				100	μA	V <sub>R</sub> =5V			
Output phototransistor										
Collector Dark Current	I <sub>CEO</sub>				100	nA	V <sub>CE</sub> =10V			
Coupler										
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	LTH-209-01			0.4	V	I <sub>C</sub> =0.08mA, I <sub>F</sub> =20mA			
		LTH-1550-01			0.4		I <sub>C</sub> =0.10mA, I <sub>F</sub> =20mA			
		LTH-1650-01			0.4		I <sub>C</sub> =0.05mA, I <sub>F</sub> =20mA			
On State Collector Current	I <sub>C(ON)</sub>	LTH-209-01	160			μA	NOTE1			
			LTH-1550-01	200	400			400	NOTE2	BINA
				300				600		BINB
		500		1000	BINC					
		LTH-1650-01	800		1600		NOTE3	BIND		
			100		300			BINA		
			200		600			BINB		
				400			1200		BINC	
		Response Time	Rise Time	t <sub>r</sub>			3	15	μs	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA R <sub>L</sub> =100 Ω
Fall Time	t <sub>f</sub>			4	20					

NOTE1: V<sub>CE</sub>=5V, I<sub>F</sub>=20mA, d=3.81MM, 90% Reflectance White Paper

NOTE2: V<sub>CE</sub>=5V, I<sub>F</sub>=20mA, d=3.50MM, 90% Reflectance White Paper

NOTE3: V<sub>CE</sub>=5V, I<sub>F</sub>=20mA, d=3.00MM, 90% Reflectance White Paper



# Typical Electrical/Optical Characteristic Curves (25°C Ambient Temperature Unless Otherwise Noted)

Fig.1 Power Dissipation vs. Ambient Temperature

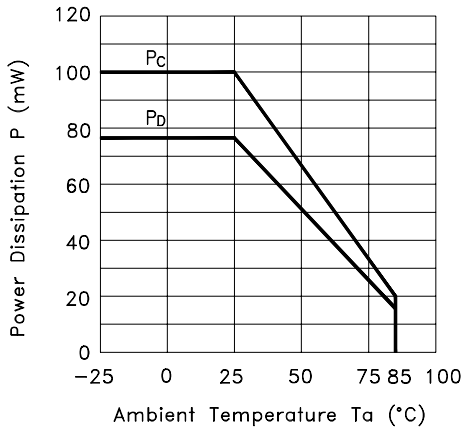


Fig.2 Forward Current vs. Forward Voltage

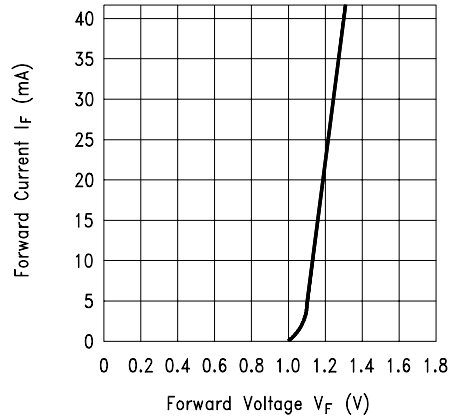


Fig.3 Collector Current vs. Collector-emitter Voltage

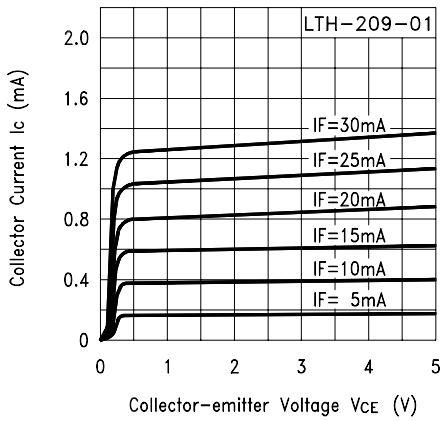


Fig.4 Collector Current vs. Collector-emitter Voltage

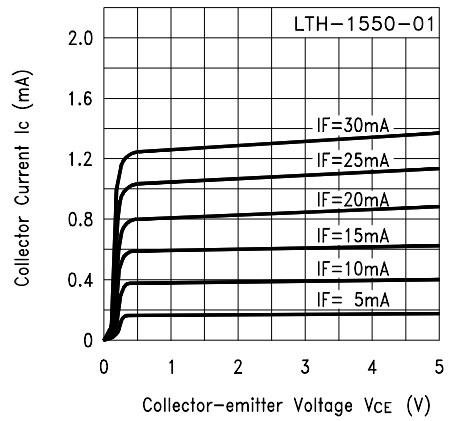


Fig.5 Collector Current vs. Collector-emitter Voltage

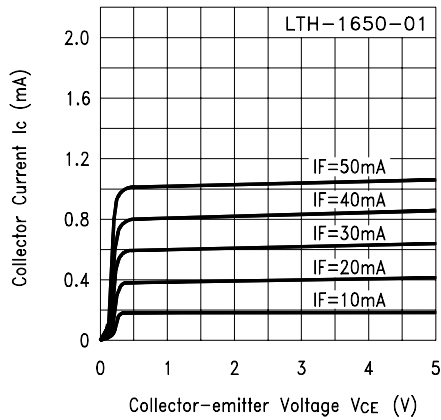
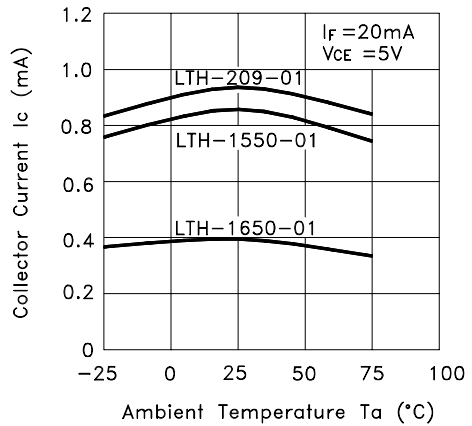


Fig.6 Collector Current vs. Ambient Temperature



# Typical Electrical/Optical Characteristic Curves (25°C Ambient Temperature Unless Otherwise Noted)

Fig.7 Collector-emitter Saturation Voltage vs. Ambient Temperature

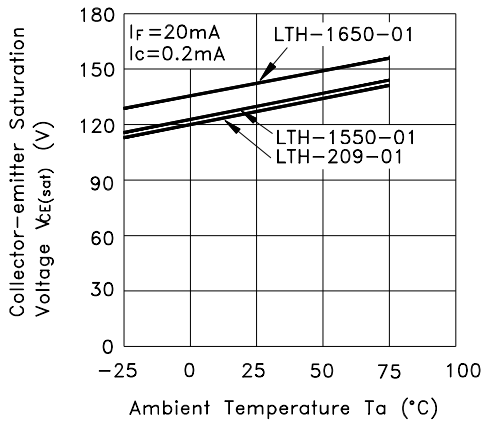


Fig.8 Relative Collector Current vs. Object Distance

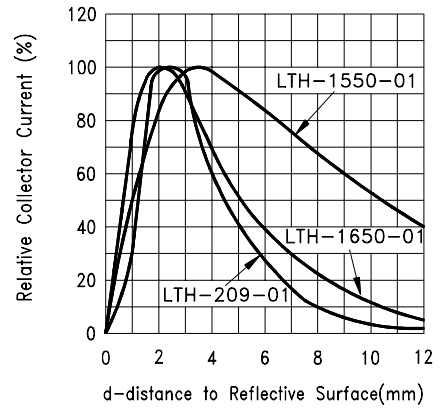
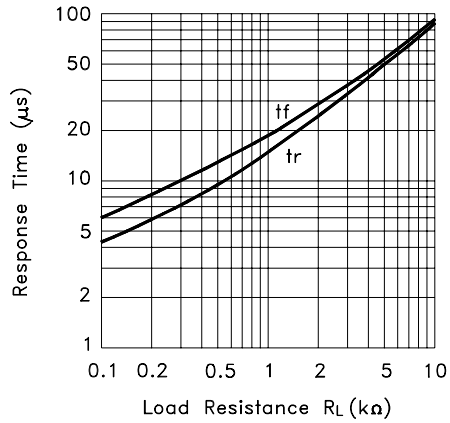


Fig.9 Response Time vs. Load Resistance



Test Circuit for Response Time

